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# FDB031N08

## N-Channel PowerTrench® MOSFET

### 75 V, 235 A, 3.1 mΩ

#### Features

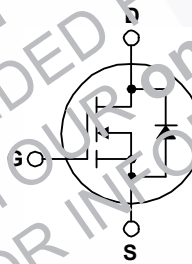
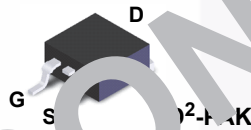
- $R_{DS(on)} = 2.4 \text{ m}\Omega$  (Typ.) @  $V_{GS} = 10 \text{ V}$ ,  $I_D = 75 \text{ A}$
- Fast Switching Speed
- Low Gate Charge
- High Performance Trench Technology for Extremely Low  $R_{DS(on)}$
- High Power and Current Handling Capability
- RoHS Compliant

#### Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

#### Applications

- Synchronous Rectification: ATX / Server / Telecom PSU
- Battery Protection Circuit
- Motor Drivers and Uninterruptible Power Supplies



#### MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	FDB031N08	Unit
$V_{DS}$	Drain-Source Voltage	75	V
$V_{GS}$	Gate to Source Voltage	$\pm 20$	V
$I_D$	Drain Current	Continuous ( $T_C = 25^\circ\text{C}$ , Silicon Limited)	235
		Continuous ( $T_C = 100^\circ\text{C}$ , Silicon Limited)	165
		Continuous ( $T_C = 25^\circ\text{C}$ , Package Limited)	120
$I_{DM}$	Drain Current - Pulsed (Note 1)	940	A
$E_{AS}$	Single Pulsed Avalanche Energy (Note 2)	1995	mJ
$dv/dt$	Peak Diode Recovery $dv/dt$ (Note 3)	5.5	V/ns
$P_D$	Power Dissipation ( $T_C = 25^\circ\text{C}$ )	375	W
		- Derate Above $25^\circ\text{C}$	2.5
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +175	$^\circ\text{C}$
$T_L$	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds	300	$^\circ\text{C}$

#### Thermal Characteristics

Symbol	Parameter	FDB031N08	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.4	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDB031N08	FDB031N08	D <sup>2</sup> -PAK	Tape and Reel	330 mm	24 mm	800 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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### Off Characteristics

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{V}, T_C = 25^\circ\text{C}$	75	-	-	V
$\Delta BV_{DSS} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$ , Referenced to $25^\circ\text{C}$	-	0.05	-	$V/^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 75 \text{V}, V_{GS} = 0 \text{V}$	-	-	1	$\mu\text{A}$
		$V_{DS} = 75 \text{V}, T_C = 150^\circ\text{C}$	-	-	500	$\mu\text{A}$
$I_{GSS}$	Gate to Body Leakage Current	$V_{GS} = \pm 20 \text{V}, V_{DS} = 0 \text{V}$	-	-	$\pm 100$	nA

### On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	2.5	3.5	4.5	V
$R_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{V}, I_D = 75 \text{A}$	-	2.4	3.1	$\text{m}\Omega$
$g_{FS}$	Forward Transconductance	$V_{DS} = 10 \text{V}, I_D = 75 \text{A}$	-	130	-	S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 25 \text{V}, V_{GS} = 0 \text{V}, f_r = 1 \text{MHz}$	-	1100	15100	pF
$C_{oss}$	Output Capacitance	$V_{GS} = 0 \text{V}, V_{DS} = 75 \text{V}, f_r = 1 \text{MHz}$	-	1360	1810	pF
$C_{rss}$	Reverse Transfer Capacitance	$V_{GS} = 0 \text{V}, V_{DS} = 75 \text{V}, f_r = 1 \text{MHz}$	-	595	800	pF
$Q_{g(tot)}$	Total Gate Charge at 10V	$V_{DS} = 60 \text{V}, I_D = 75 \text{A}, V_{GS} = 10 \text{V}$	-	169	220	nC
$Q_{gs}$	Gate to Source Gate Charge	$V_{GS} = 10 \text{V}$	-	60	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge	(Note 4)	-	47	-	nC

### Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{GS} = 10 \text{V}, V_{DS} = 60 \text{V}, I_D = 75 \text{A}, R_G = 25 \Omega$	-	230	470	ns
$t_r$	Turn-On Rise Time	$V_{GS} = 10 \text{V}, V_{DS} = 60 \text{V}, I_D = 75 \text{A}, R_G = 25 \Omega$	-	191	392	ns
$t_{d(off)}$	Turn-Off Delay Time	$V_{GS} = 10 \text{V}, V_{DS} = 60 \text{V}, I_D = 75 \text{A}, R_G = 25 \Omega$	-	335	680	ns
$t_f$	Turn-Off Fall Time	(Note 4)	-	121	252	ns

### Drain-Source Diode Characteristics

$I_{SD}$	Maximum Continuous Drain to Source Diode Forward Current	$V_{GS} = 0 \text{V}, I_{SD} = 75 \text{A}$	-	-	235	A
$I_{SM}$	Maximum Pulsed Drain to Source Diode Forward Current	$V_{GS} = 0 \text{V}, I_{SD} = 75 \text{A}$	-	-	940	A
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS} = 0 \text{V}, I_{SD} = 75 \text{A}$	-	-	1.3	V
$t_{rr}$	Reverse Recovery Time	$V_{GS} = 0 \text{V}, I_{SD} = 75 \text{A}, di_F/dt = 100 \text{A}/\mu\text{s}$	-	53	-	ns
$Q_{rr}$	Reverse Recovery Charge	$V_{GS} = 0 \text{V}, I_{SD} = 75 \text{A}, di_F/dt = 100 \text{A}/\mu\text{s}$	-	77	-	nC

#### Notes:

1. Repetitive rating; pulse-width limited by maximum junction temperature.
2.  $L = 0.71 \text{ mH}, I_{AS} = 75 \text{A}, V_{DD} = 50 \text{V}, R_G = 25 \Omega$ , starting  $T_J = 25^\circ\text{C}$ .
3.  $I_{SD} \leq 75 \text{A}, di/dt \leq 200 \text{A}/\mu\text{s}, V_{DD} \leq BV_{DSS}$ , starting  $T_J = 25^\circ\text{C}$ .
4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

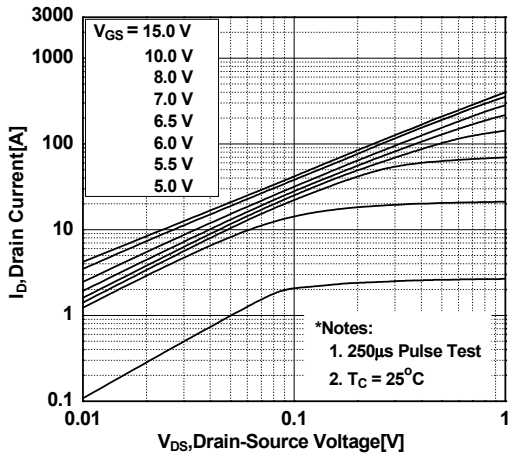


Figure 2. Transfer Characteristics

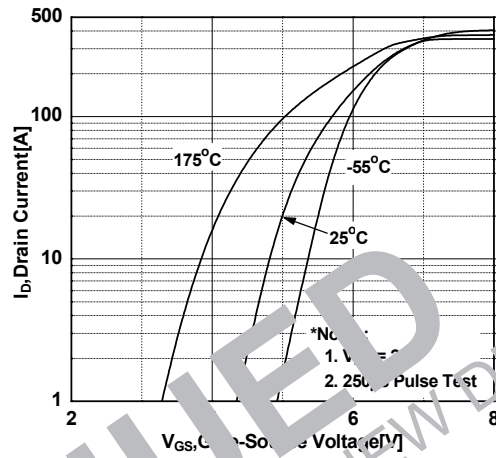


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

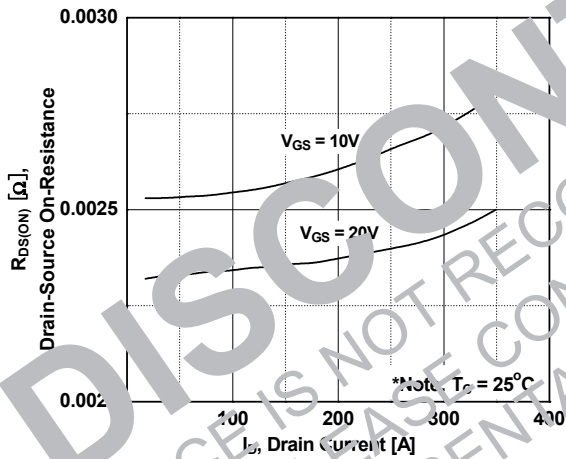


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

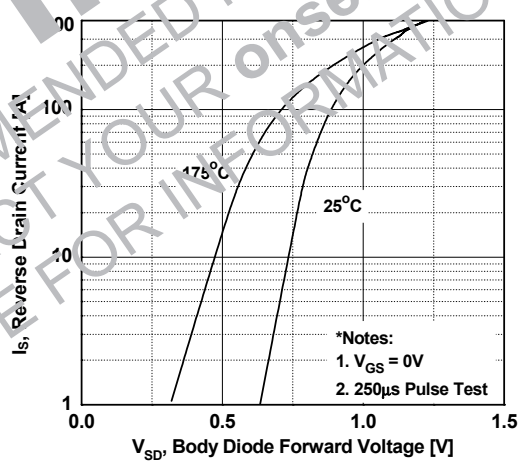


Figure 5. Capacitance Characteristics

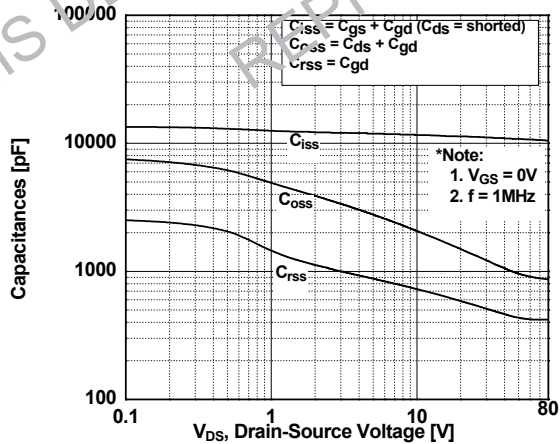
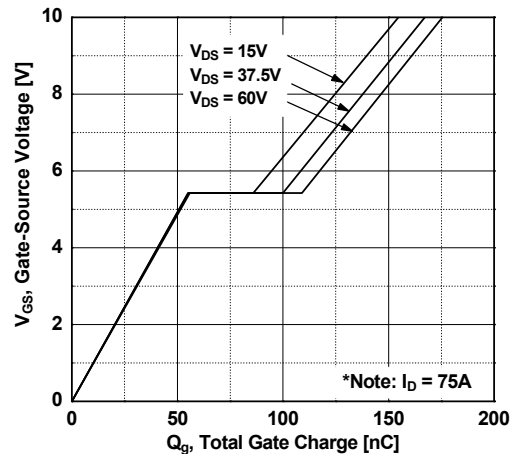


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

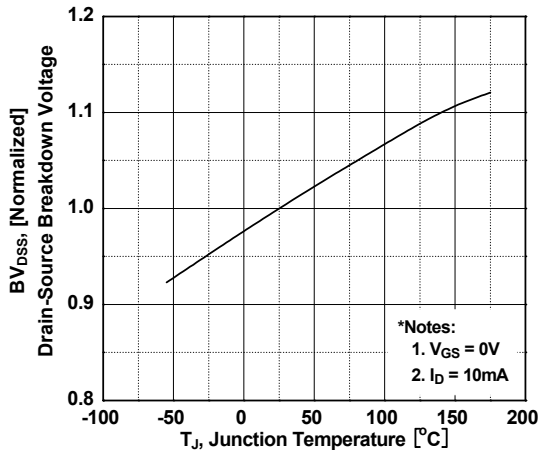


Figure 8. On-Resistance Variation vs. Temperature

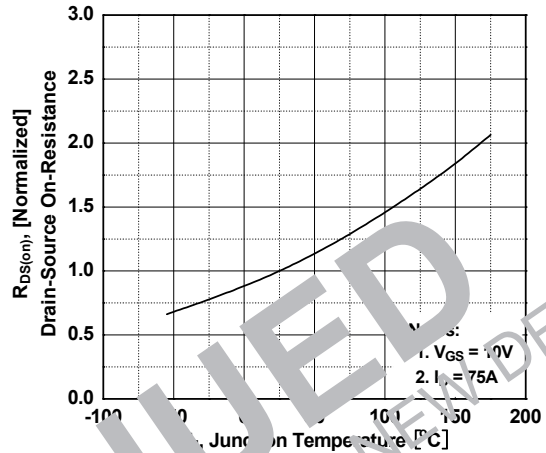


Figure 9. Maximum Safe Operating Area

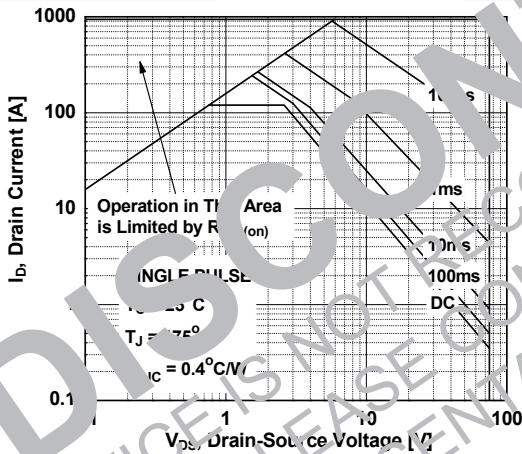


Figure 10. Maximum Drain Current vs. Case Temperature

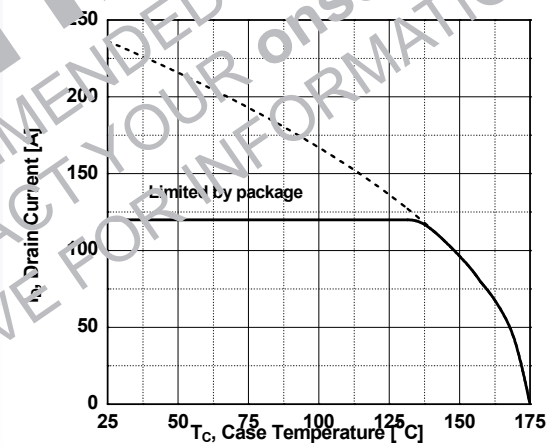
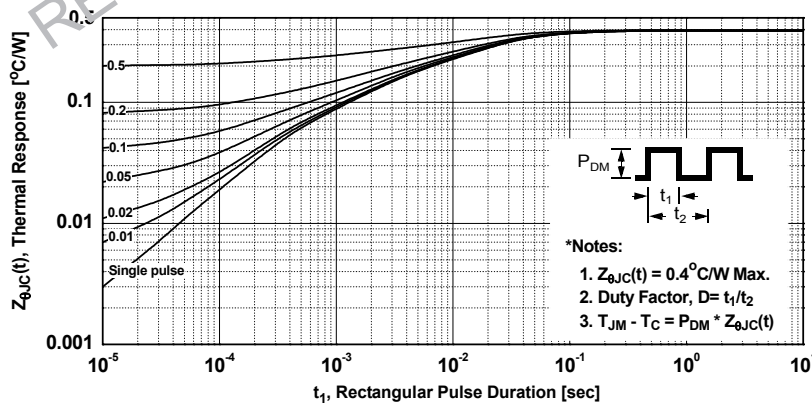


Figure 11. Transient Thermal Response Curve



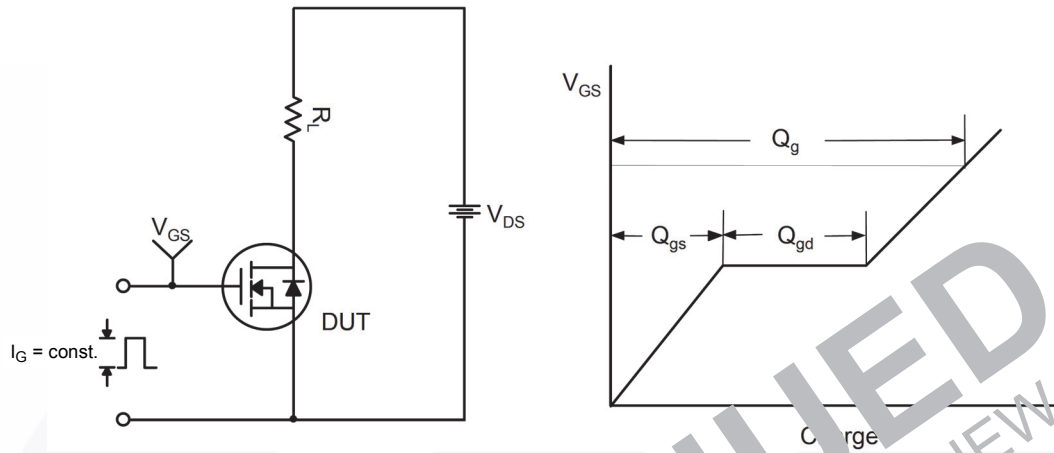


Figure 12. Gate Charge Test Circuit & Waveform



Figure 13. Resistive Switching Test Circuit & Waveforms

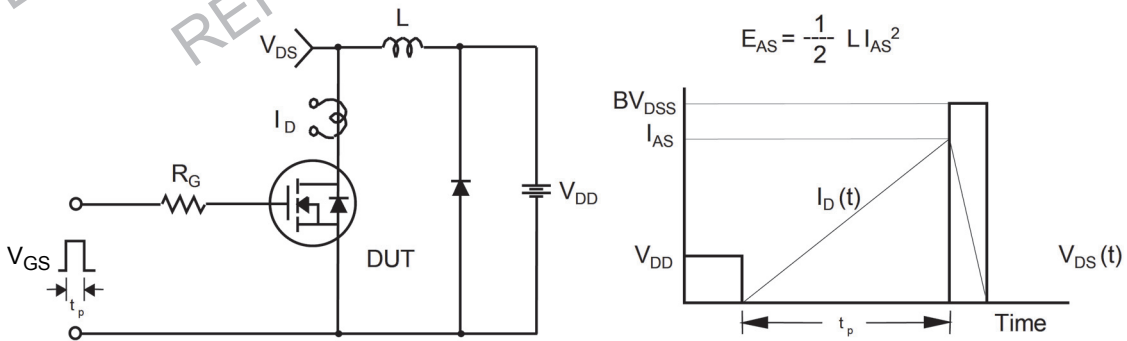


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

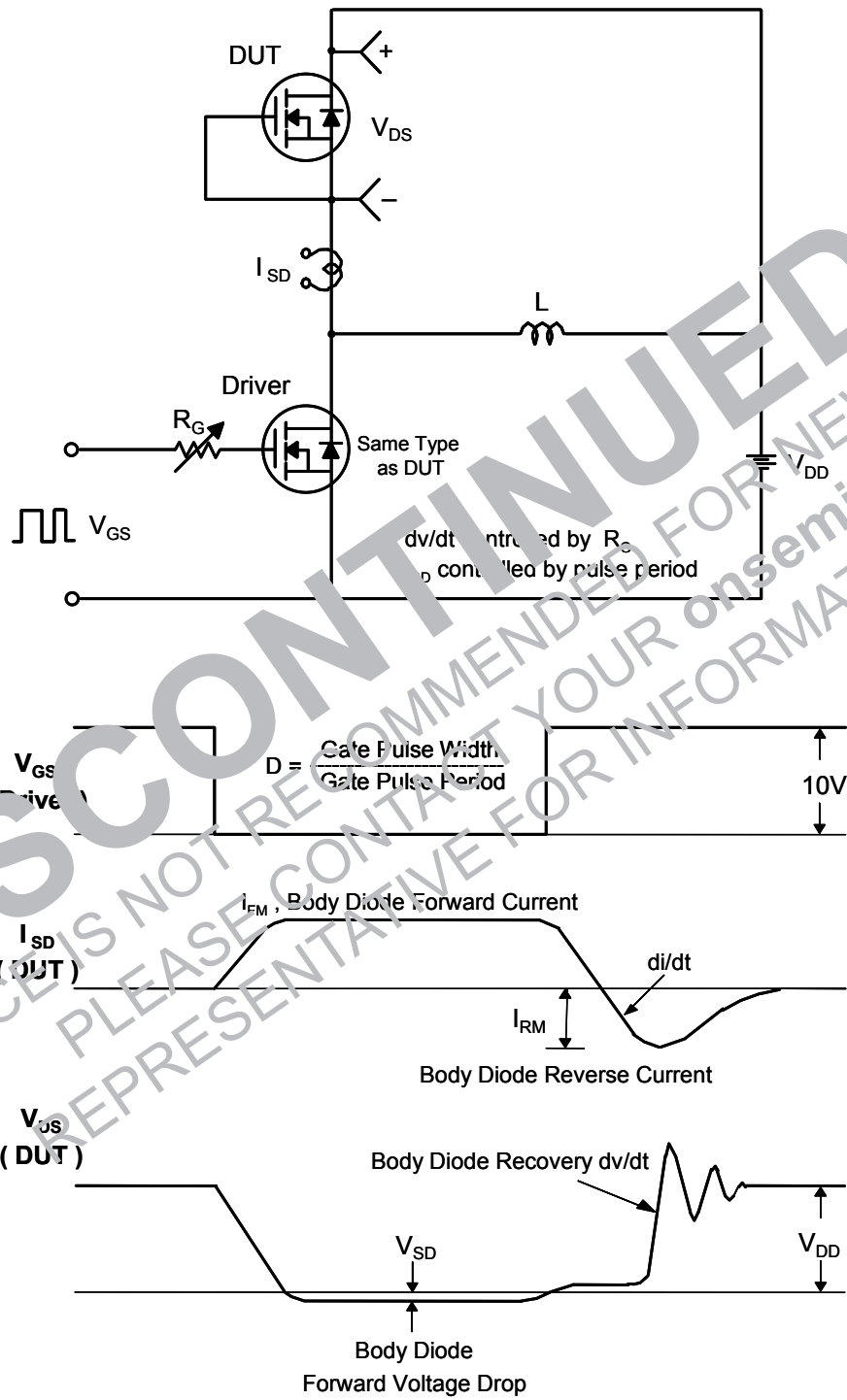


Figure 15. Peak Diode Recovery  $dv/dt$  Test Circuit & Waveforms

Mechanical Dimensions

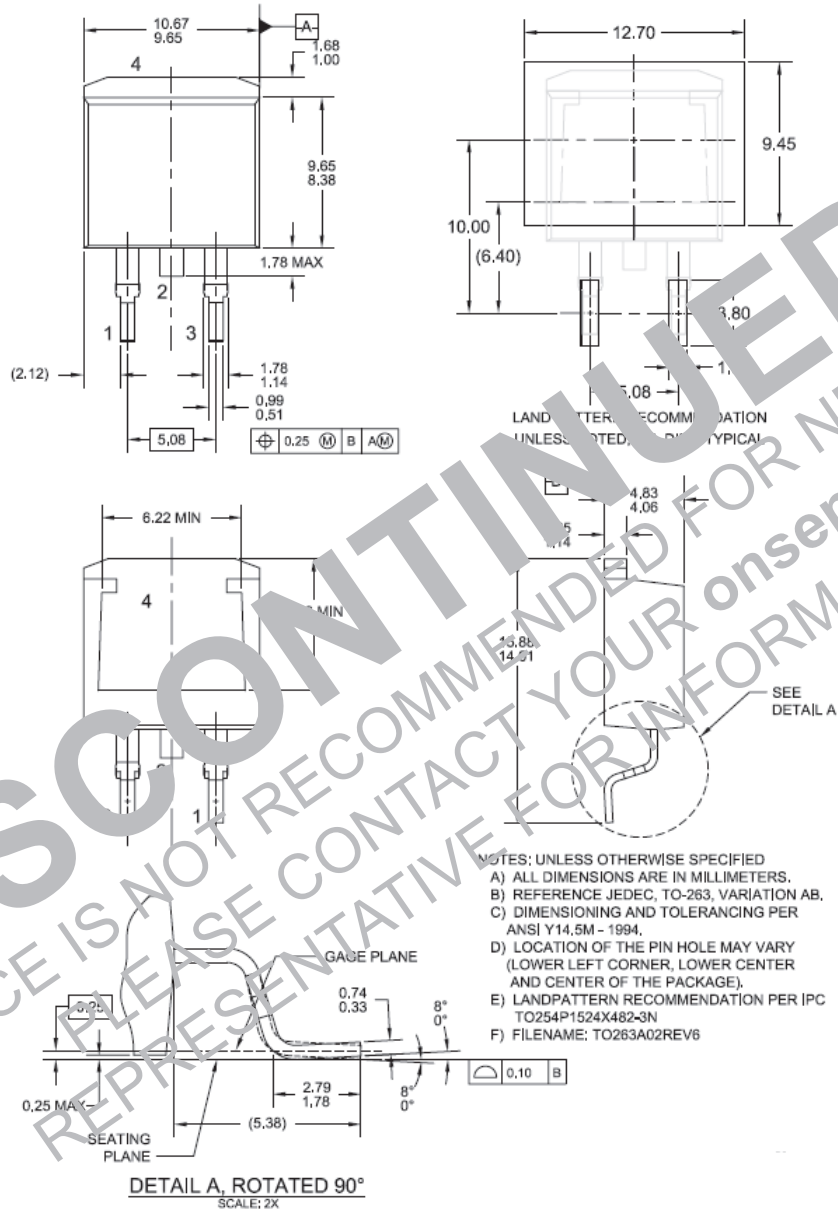


Figure 16. TO263 (D<sup>2</sup>PAK), Molded, 2-Lead, Surface Mount

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